

Zero Recovery Silicon Carbide Schottky Diode

PRODUCT APPLICATIONS

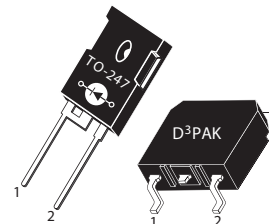
- Anti-Parallel Diode
- Switchmode Power Supply
- Inverters
- Power Factor Correction (PFC)

PRODUCT FEATURES

- Zero Recovery Times (t_{rr})
- Popular TO-247 Package or surface mount D³PAK package
- Low Forward Voltage
- Low Leakage Current

PRODUCT BENEFITS

- Higher Reliability Systems
- Minimizes or eliminates snubber



1 - Cathode
2 - Anode
Back of Case - Cathode

MAXIMUM RATINGS

$T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Characteristic / Test Conditions		Ratings	Unit
V _R	Maximum D.C. Reverse Voltage		1200	Volts
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			
V _{RWM}	Maximum Working Peak Reverse Voltage			
I _F	Maximum D.C. Forward current	T _C = 25°C	99	Amps
		T _C = 135°C	29	
I _{FRM}	Repetitive Peak Forward Suge Current (T _J = 45°C, t _p = 10ms, Half Sine Wave)		150	
I _{FSM}	Non-Repetitive Forward Surge Current (T _J = 25°C, t _p = 10ms, Half Sine)		330	
P _{tot}	Power Dissipation	T _C = 25°C	291	W
		T _C = 125°C	93	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to 150	°C
T _L	Lead Temperature for 10 Seconds		300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		Min	Typ	Max	Unit
V_F	Forward Voltage	$I_F = 30\text{A}$, $T_J = 25^\circ\text{C}$		1.5	1.8	Volts
		$I_F = 30\text{A}$, $T_J = 150^\circ\text{C}$		2.1		
I_{RM}	Maximum Reverse Leakage Current	$V_R = 1200\text{V}$, $T_J = 25^\circ\text{C}$			600	μA
		$V_R = 1200\text{V}$, $T_J = 150^\circ\text{C}$			3000	
Q_c	Total Capacitive Charge $V_R = 800\text{V}$, $I_F = 30\text{A}$, $di/dt = -100\text{A}/\mu\text{s}$, $T_J = 25^\circ\text{C}$			200		nC
C_T	Junction Capacitance $V_R = 0\text{V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{MHz}$			2100		pF
	Junction Capacitance $V_R = 200\text{V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{MHz}$			228		
	Junction Capacitance $V_R = 400\text{V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{MHz}$			167		

Symbol	Characteristic / Test Conditions	Min	Typ	Max	Unit
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			0.43	°C/W
W_T	Package Weight		0.22		oz
			5.9		g
Torque	Maximum Mounting Torque			10	lb·in
				1.1	N·m

Microsemi reserves the right to change, without notice, the specifications and information contained herein.

TYPICAL PERFORMANCE CURVES

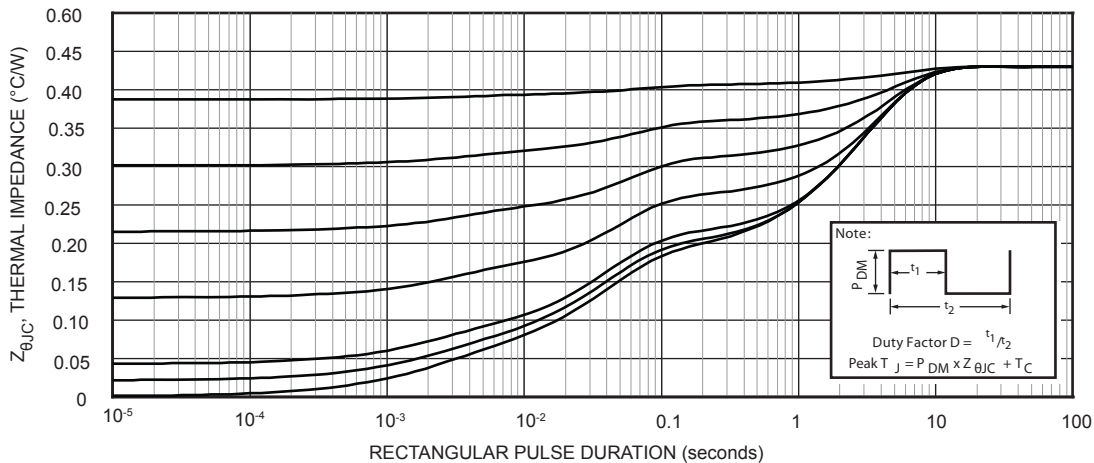


FIGURE 1. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

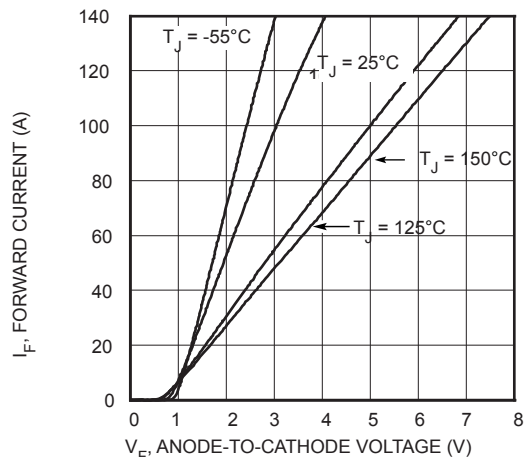


FIGURE 2, Forward Current vs. Forward Voltage

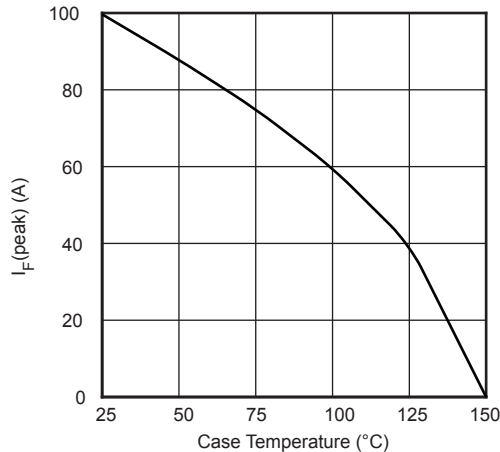
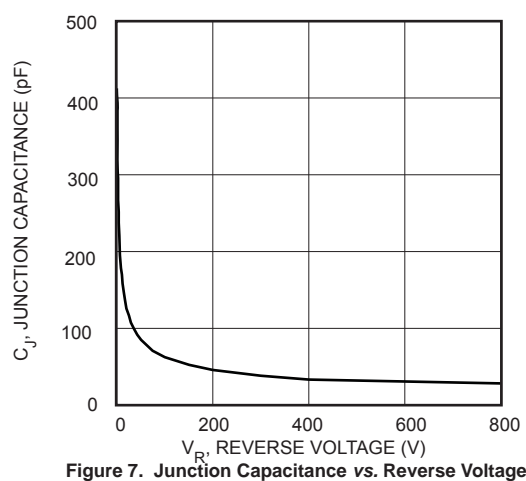
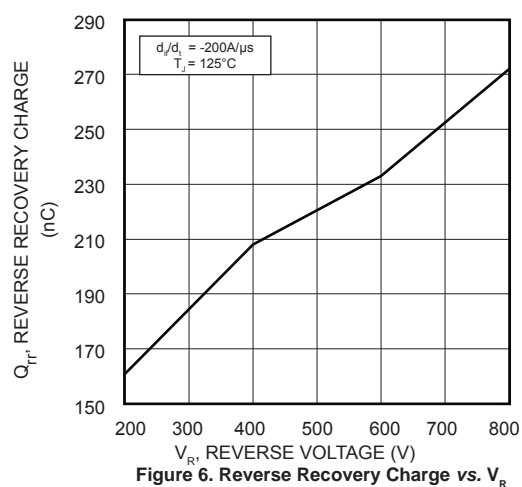
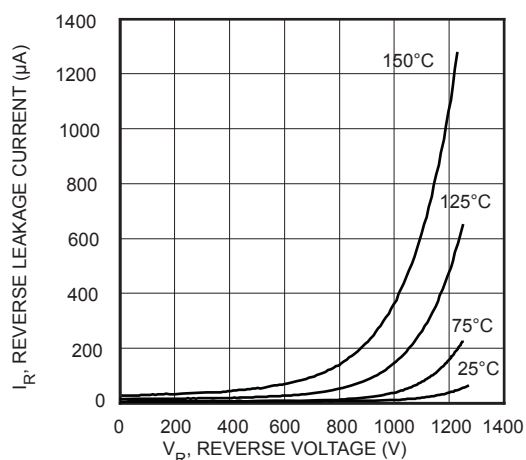
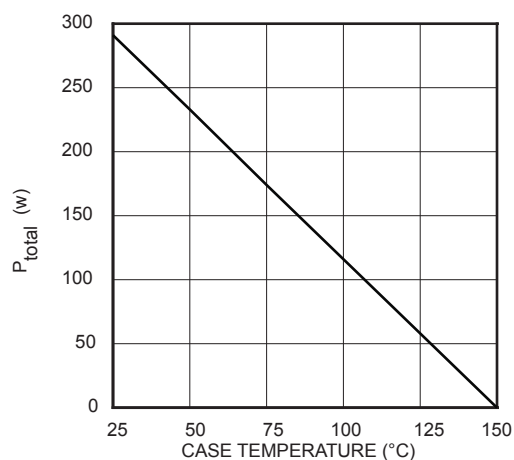
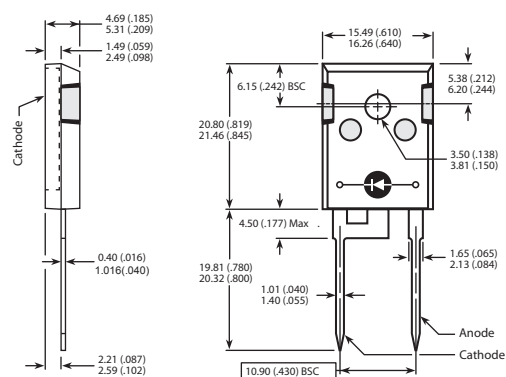


FIGURE 3, Maximum Forward Current vs. Case Temperature

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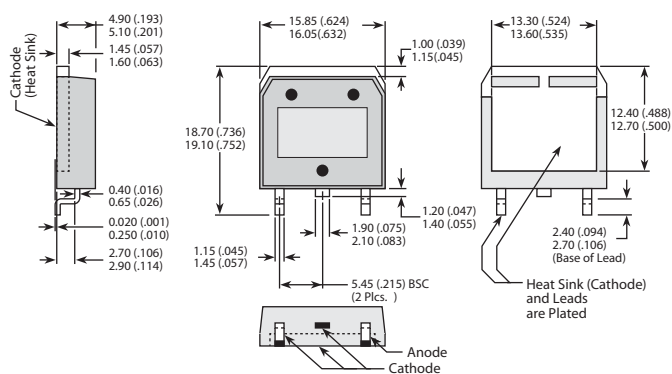


TO-247 Package Outline



Dimensions in Millimeters and (Inches)

D³PAK Package Outline



Dimensions in Millimeters and (Inches)

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